

PBSS4360X 60 V, 3 A NPN low VCEsat BISS transistor

9 June 2017

Product data sheet

## 1. General description

NPN low V<sub>CEsat</sub> Breakthrough in Smal Signal (BISS) transitor in a medium power SOT89 (SC-62) flat lead Surface-Mounted Device (SMD) plastic package.

PNP complement: PBSS5360X

## 2. Features and benefits

- Low collector-emitter saturation voltage V<sub>CEsat</sub> •
- High collector current capability  $I_{C}$  and  $I_{CM}$ •
- · High energy efficiency due to less heat generation
- AEC-Q101 qualified .

## 3. Applications

- DC-to-DC conversion
- Supply line switching
- Battery charger
- LCD backlighting
- Driver in low supply voltage applications (e.g. lamps and LEDs)
- Inductive load driver (e.g. relays, buzzers and motors) •

## 4. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-	60	V
I <sub>C</sub>	collector current			-	-	3	А
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-	6	А
R <sub>CEsat</sub>	collector-emitter saturation resistance	$I_{C}$ = 2 A; $I_{B}$ = 200 mA; $T_{amb}$ = 25 °C	[1]	-	-	140	mΩ

[1] Pulse test:  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ 

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# 5. Pinning information

Table 2	. Pinning inf	formation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E	emitter		C
2	С	collector		в-
3	В	base		в — Ба Е
			SOT89	sym123

# 6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
PBSS4360X	SOT89	plastic, surface-mounted package; 3 leads; 1.5 mm pitch; 4.5 mm x 2.5 mm x 1.5 mm body	SOT89			

# 7. Marking

Table 4. Marking codes					
	Type number	Marking code			
	PBSS4360X	S40			

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## 8. Limiting values

#### Table 5. Limiting values

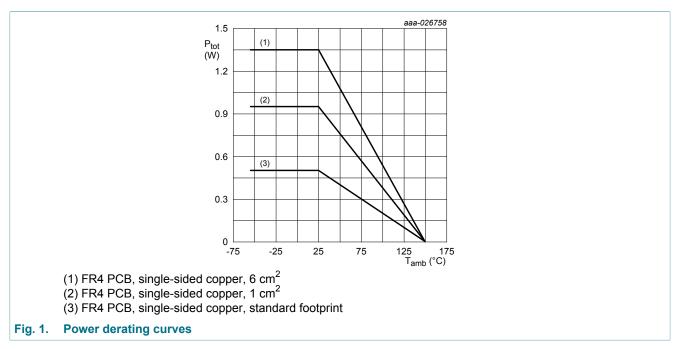
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Мах	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter		-	80	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	60	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	7	V
I <sub>C</sub>	collector current			-	3	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	6	А
I <sub>B</sub>	base current			-	500	mA
I <sub>BM</sub>	peak base current	single pulse; t <sub>p</sub> ≤ 1 ms		-	1	Α
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	[1]	-	500	mW
			[2]	-	950	mW
			[3]	-	1.35	W
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint. [1]

Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated; mounting pad for collector 1 cm<sup>2</sup>. Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated; mounting pad for collector 6 cm<sup>2</sup>. [2]

[3]



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## 9. Thermal characteristics

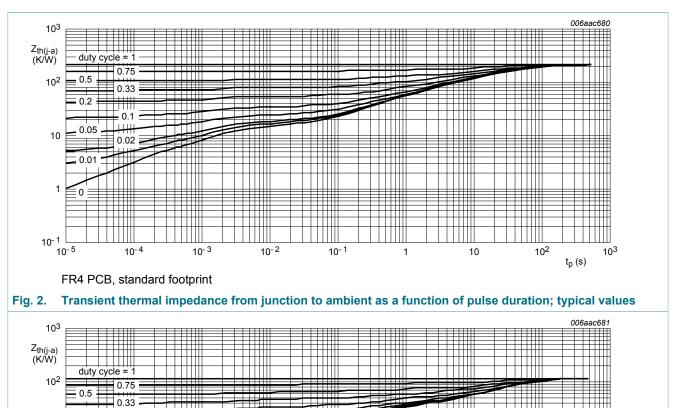
Table 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
	thermal resistance	in free air	[1]	-	-	250	K/W
	from junction to ambient		[2]	-	-	132	K/W
			[3]	-	-	93	K/W

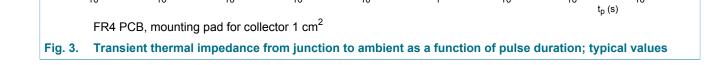
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 1 cm<sup>2</sup>.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 6 cm<sup>2</sup>.

10<sup>-2</sup>





10-1

1

10<sup>3</sup>

10

10<sup>2</sup>

02

0.05

0.01

10

1

10<sup>- 1</sup>

10-5

**-** 0.1

0.02

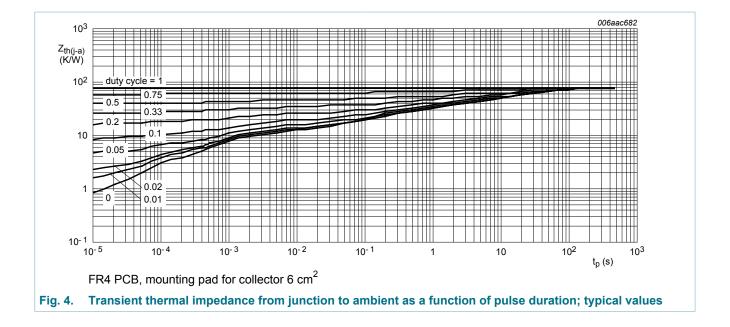
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PBSS4360X

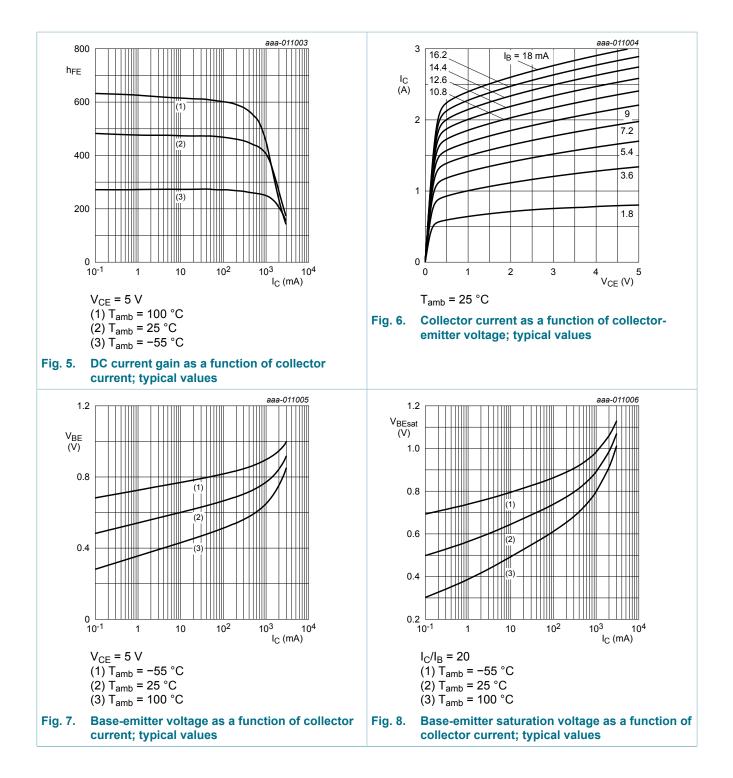
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# **10. Characteristics**

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off	$V_{CB}$ = 48 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	100	nA
	current	V <sub>CB</sub> = 48 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C		-	-	50	μA
I <sub>CES</sub>	collector-emitter cut-off current	$V_{CE}$ = 48 V; $V_{BE}$ = 0 V; $T_{amb}$ = 25 °C		-	-	100	nA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB}$ = 5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	100	nA
h <sub>FE</sub>	DC current gain	$V_{CE}$ = 5 V; I <sub>C</sub> = 50 mA; T <sub>amb</sub> = 25 °C		200	-	-	
		$V_{CE}$ = 5 V; I <sub>C</sub> = 500 mA; T <sub>amb</sub> = 25 °C	[1]	200	-	-	
		V <sub>CE</sub> = 5 V; I <sub>C</sub> = 1 A; T <sub>amb</sub> = 25 °C	[1]	200	-	-	
		$V_{CE}$ = 5 V; I <sub>C</sub> = 2 A; T <sub>amb</sub> = 25 °C	[1]	120	-	-	
		$V_{CE}$ = 5 V; $I_C$ = 3 A; $T_{amb}$ = 25 °C	[1]	75	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_{C}$ = 500 mA; $I_{B}$ = 50 mA; $T_{amb}$ = 25 °C	[1]	-	-	75	mV
		$I_{C}$ = 1 A; $I_{B}$ = 100 mA; $T_{amb}$ = 25 °C	[1]	-	-	150	mV
		$I_C$ = 2 A; $I_B$ = 200 mA; $T_{amb}$ = 25 °C	[1]	-	-	275	mV
		$I_{C}$ = 3 A; $I_{B}$ = 300 mA; $T_{amb}$ = 25 °C	[1]	-	-	400	mV
R <sub>CEsat</sub>	collector-emitter saturation resistance	$I_{C}$ = 2 A; $I_{B}$ = 200 mA; $T_{amb}$ = 25 °C	[1]	-	-	140	mΩ
V <sub>BEsat</sub>	base-emitter saturation voltage	$I_{C}$ = 1 A; $I_{B}$ = 100 mA; $T_{amb}$ = 25 °C	[1]	-	-	1.2	V
V <sub>BEon</sub>	base-emitter turn-on voltage	$V_{CE}$ = 5 V; $I_C$ = 1 A; $T_{amb}$ = 25 °C	[1]	-	-	1.1	V
f <sub>T</sub>	transition frequency	$V_{CE}$ = 10 V; I <sub>C</sub> = 50 mA; f = 100 MHz; T <sub>amb</sub> = 25 °C		75	145	-	MHz
C <sub>c</sub>	collector capacitance	V <sub>CB</sub> = 10 V; I <sub>E</sub> = 0 A; i <sub>e</sub> = 0 A; f = 1 MHz; T <sub>amb</sub> = 25 °C		-	11	14	pF

[1] Pulse test:  $t_p \le 300 \ \mu s; \delta \le 0.02$ 

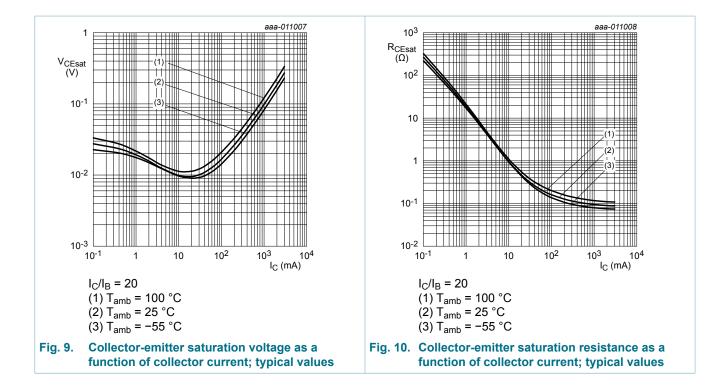
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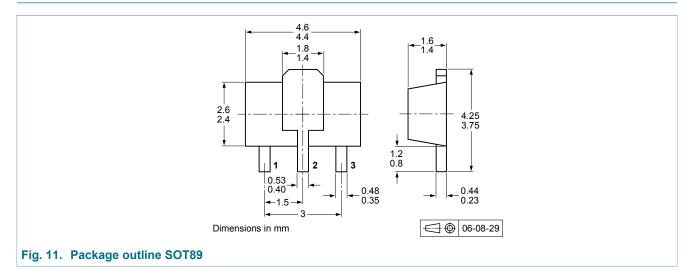
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# 11. Test information

### **Quality information**

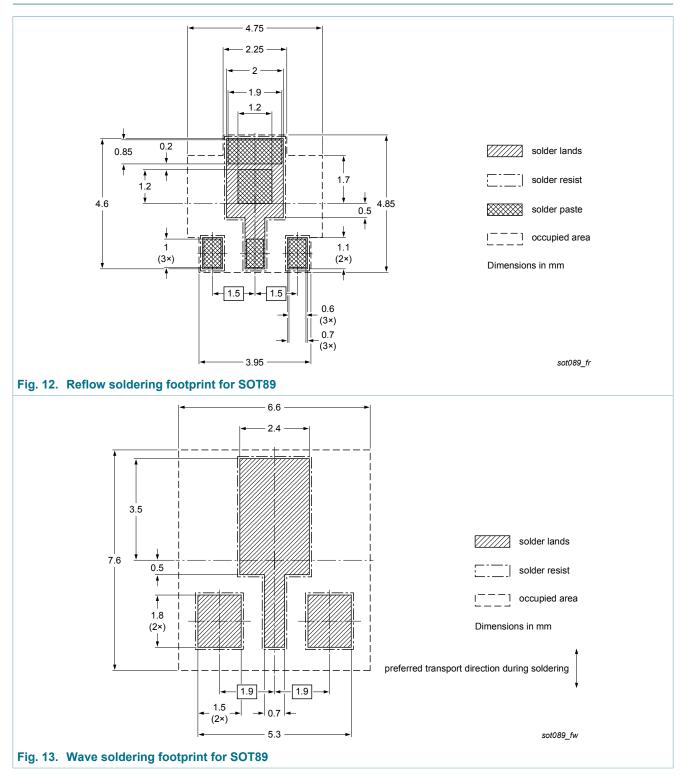
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

# 12. Package outline



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## 13. Soldering



## 60 V, 3 A NPN low VCEsat BISS transistor

# 14. Revision history

Table 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PBSS4360X v.1	20170609	Product data sheet	-	-		

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## 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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